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High Performance Schottky Rectifier, 10 A



PRIMARY CHARACTERISTICS							
I _{F(AV)}	10 A						
V_R	35 V, 45 V						
V _F at I _F	0.57 V						
I _{RM}	15 mA at 125 °C						
T _J max.	150 °C						
E _{AS}	8 mJ						
Package	D ² PAK (TO-263AB)						
Circuit configuration	Single						

FEATURES

- 150 °C T_J operation
- TO-220 and D2PAK packages
- Low forward voltage drop
- High frequency operation



- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I _{F(AV)}	Rectangular waveform	10	Δ.					
I _{FRM}	T _C = 135 °C	20	A					
V _{RRM}		35/45	V					
I _{FSM}	t _p = 5 μs sine	1060	A					
V _F	10 A _{pk} , T _J = 125 °C	0.57	V					
TJ	Range	-65 to +150	C°					

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-MBRB1035-M3	VS-MBRB1045-M3	UNITS				
Maximum DC reverse voltage	V_{R}	35	45	V				
Maximum working peak reverse voltage	V_{RWM}	35	45	V				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CON	VALUES	UNITS				
Maximum average forward current	I _{F(AV)}	T _C = 135 °C, rated V _R	10					
Peak repetitive forward current	I _{FRM}	Rated V _R , square wave, 20 kl	Rated V _R , square wave, 20 kHz, T _C = 135 °C					
Non-repetitive surge current	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	1060	А			
		Surge applied at rated load conditions halfwave, single phase, 60 Hz		150				
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 2 \text{A}, L = 4 \text{m}$	8	mJ				
Repetitive avalanche current	I _{AR}	Current decaying linearly to z Frequency limited by T _J maxi	2	Α				



VS-MBRB1035-M3, VS-MBRB1045-M3

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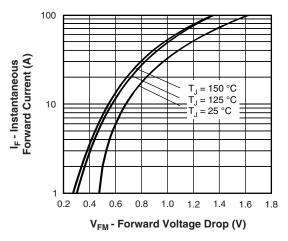
ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST C	VALUES	UNITS			
		20 A	T _J = 25 °C	0.84			
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	T _{.1} = 125 °C	0.57	V		
		20 A	- IJ = 125 C	0.72			
Maximum instantaneous reverse	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.1	mA		
current	'RM '''	T _J = 125 °C	Hateu DC voltage	15			
Threshold voltage	V _{F(TO)}	T - T maximum	$T_J = T_J \text{ maximum}$				
Forward slope resistance	r _t	ıj = ıjınaxımum					
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal r °C	600	pF			
Typical series inductance	L _S	Measured from top of to	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs			

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temper	erature range	TJ		-65 to 150	°C	
Maximum storage tempe	rature range	T _{Stg}		-65 to 175	°C	
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	2.0	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased (Only for TO-220)	0.50	C/VV	
Approximate weight				2	g	
Approximate weight				0.07	OZ.	
Marinting torque	minimum			6 (5)	kgf · cm	
Mounting torque	maximum			12 (10)	(lbf ⋅ in)	
Marking device			Case style D ² PAK (TO-263AB)	MBRI	31035	
			Case style D-PAN (10-203AB)	MBRI	MBRB1045	

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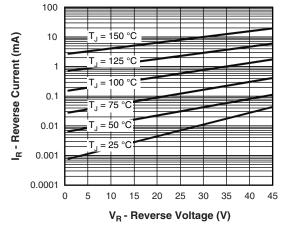


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

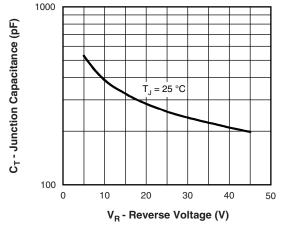


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

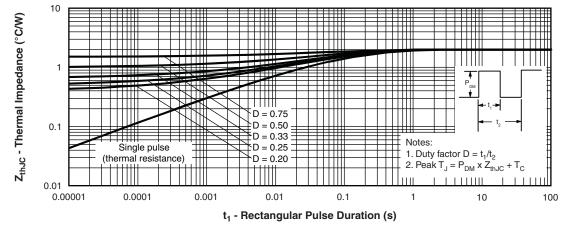


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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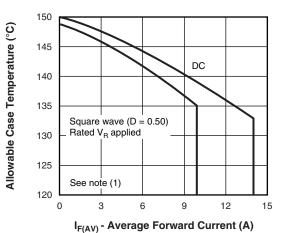


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

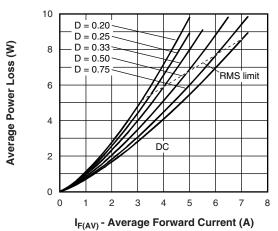
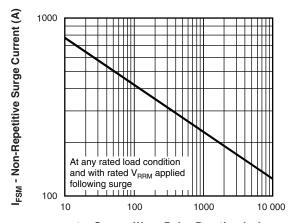


Fig. 6 - Forward Power Loss Characteristics



 t_p - Square Wave Pulse Duration (μ s) Fig. 7 - Maximum Non-Repetitive Surge Current

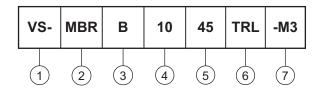
Note

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Essential part number

B = surface mount

- Current rating (10 = 10 A)

- Voltage ratings 35 = 35 V 45 = 45 V

- • None = tube

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

7 - -M3 = halogen-free, RoHS-compliant and termination lead (Pb)-free

ORDERING INFORMATION										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-MBRB1035-M3	50	1000	Antistatic plastic tubes							
VS-MBRB1035TRR-M3	800	800	13" diameter reel							
VS-MBRB1035TRL-M3	800	800	13" diameter reel							
VS-MBRB1045-M3	50	1000	Antistatic plastic tubes							
VS-MBRB1045TRR-M3	800	800	13" diameter reel							
VS-MBRB1045TRL-M3	800	800	13" diameter reel							

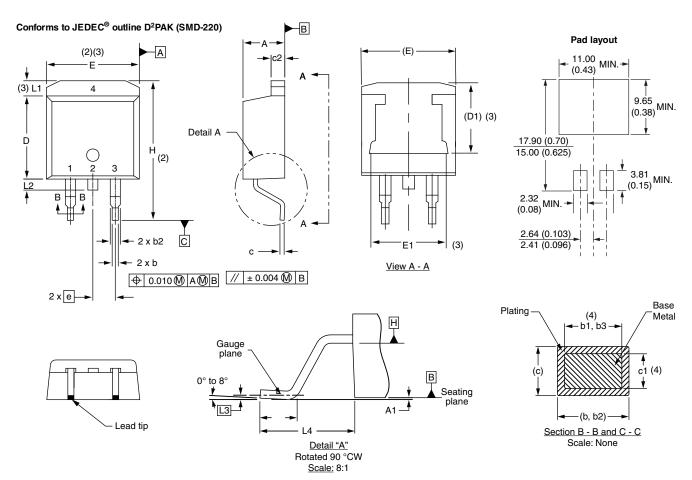
LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?96164					
Part marking information	www.vishay.com/doc?95444					
Packaging information	www.vishay.com/doc?96424					
SPICE model	www.vishay.com/doc?95293					



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	HES NOTES		SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3	
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3	
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3	
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC		
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625		
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110		
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3	
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070		
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC		
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208		

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inches
- (7) Outline conforms to JEDEC® outline TO-263AB

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